

KS54AHCT 112
KS74AHCT

Dual J-K Negative-Edge-Triggered Flip-Flops with Preset and Clear

T-46-07-07

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
- Package options include plastic "small outline" packages, standard plastic and ceramic 300-mil DIPs

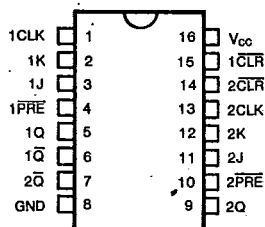
DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K, preset, clear and clock inputs and complementary outputs. The J-K inputs at each flip-flop are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

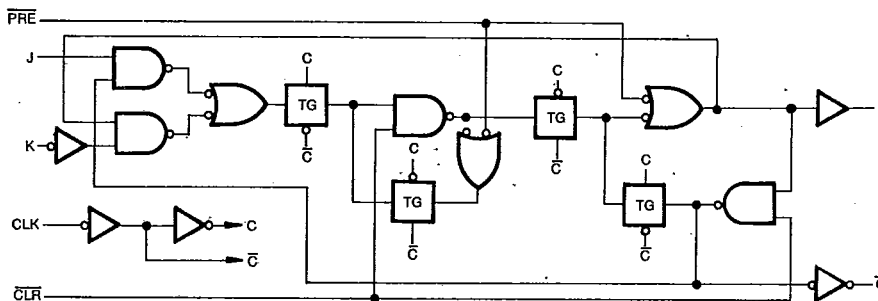


FUNCTION TABLE

Inputs					Outputs	
PRE	CLR	CLK	J	K	Q	Q-bar
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H*	H*
H	H	↓	L	L	Q ₀	Q ₀ -bar
H	H	↓	H	L	H	L
H	H	↓	L	H	L	H
H	H	↓	H	H	TOGGLE	TOGGLE
H	H	H	X	X	Q ₀	Q ₀ -bar

*Both outputs will remain high as long as PRE and CLR are low, but the output states are unpredictable if PRE and CLR go high simultaneously.

LOGIC DIAGRAM



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Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_{d1} 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

Characteristic	Symbol	Test Conditions	$T_a = 25^\circ C$			Unit	
			Typ	KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$	KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$		
Minimum High-Level Input Voltage	V_{IH}			2.0	2.0	2.0	V
Maximum Low-Level Input Voltage	V_{IL}			0.8	0.8	0.8	V
Minimum High-Level Output Voltage	V_{OH}	$V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$	V_{CC} 4.2	$V_{CC} - 0.1$ 3.98	$V_{CC} - 0.1$ 3.84	$V_{CC} - 0.1$ 3.7	V
Maximum Low-Level Output Voltage	V_{OL}	$V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$	0	0.1 0.26 0.39	0.1 0.33 0.5	0.1 0.4	V
Maximum Input Current	I_{IN}	$V_{IN}=V_{CC}$ or GND		± 0.1	± 1.0	± 1.0	μA
Maximum Quiescent Supply Current	I_{CC}	$V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$		4.0	40.0	80.0	μA
Additional Worst Case Supply Current	ΔI_{CC}	per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$		2.7	2.9	3.0	mA

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT112

Characteristic	Symbol	Conditions†	$T_a = 25^\circ\text{C}$	KS74AHCT		KS54AHCT		Unit
			$V_{CC} = 5.0\text{V}$	$T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$	$T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$			
			Typ	Min	Max	Min	Max	
Maximum Clock Frequency	f_{\max}	$C_L = 50\text{pF}$	50	30		25		MHz
Propagation Delay, CLK to Q or \bar{Q}	t_{PLH}		10		17		20	ns
	t_{PHL}		10		17		20	ns
Propagation Delay, \bar{PRE} or \bar{CLR} to Q or \bar{Q}	t_{PLH}		10		17		20	ns
	t_{PHL}		10		17		20	ns
Setup Time before $\text{CLK}\downarrow$	J or K		t_{su}	10	17		20	ns
	\bar{PRE} or \bar{CLR} Inactive		10	17		20	ns	
Hold Time, Data after $\text{CLK}\downarrow$	t_h		-3	0		0	ns	
Pulse Width	CLK High or Low	t_w	10	17		20	ns	
	\bar{PRE} or \bar{CLR} Low		6	10		15	ns	
Input Capacitance	C_{IN}		5				pF	
Power Dissipation Capacitance*	C_{PD} (per flip-flop)		40				pF	

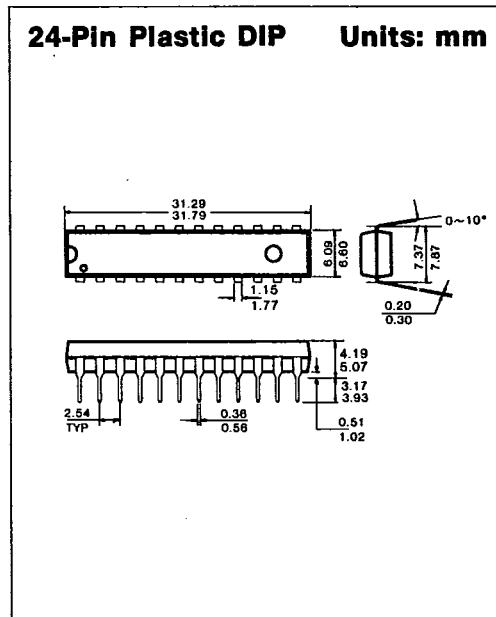
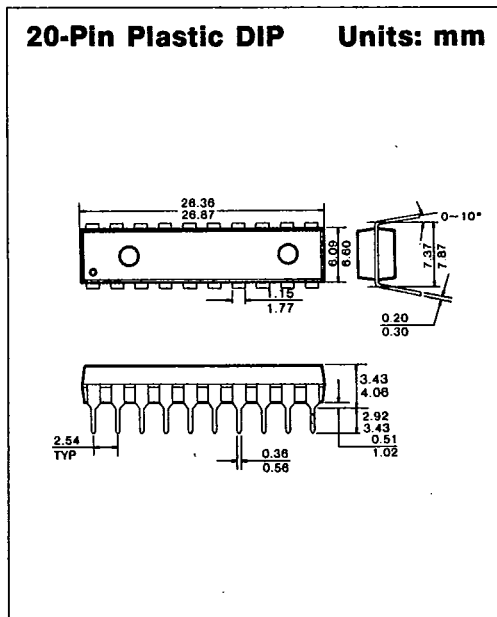
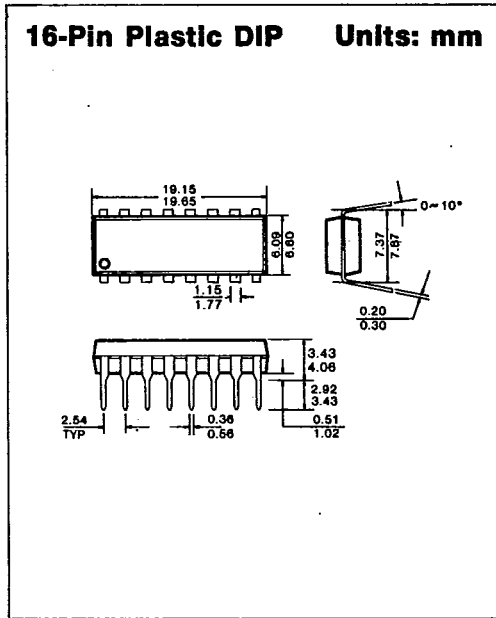
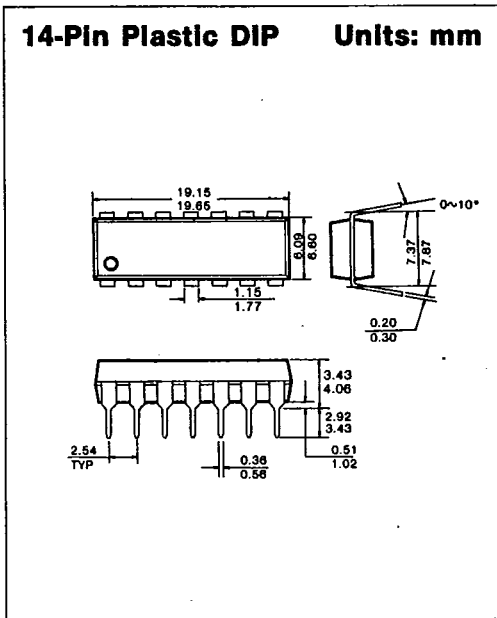
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

PACKAGE DIMENSIONS

T-90-20

1. PLASTIC PACKAGES



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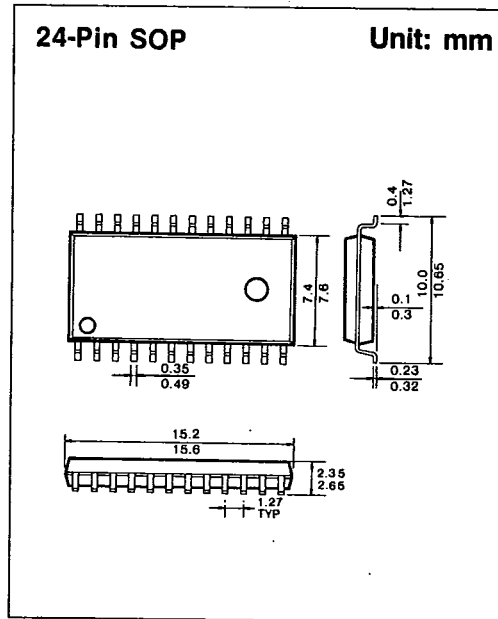
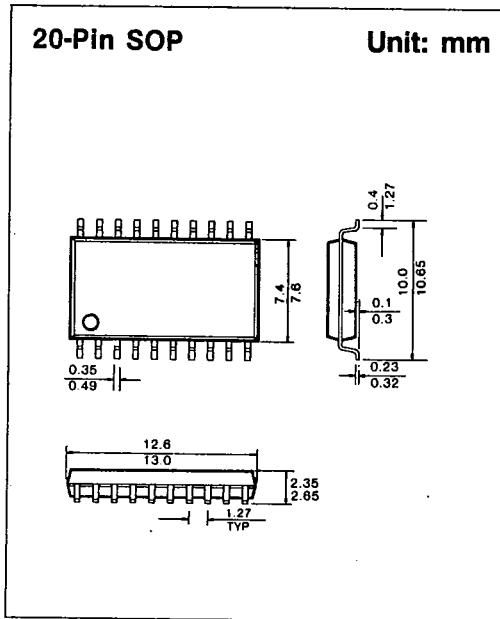
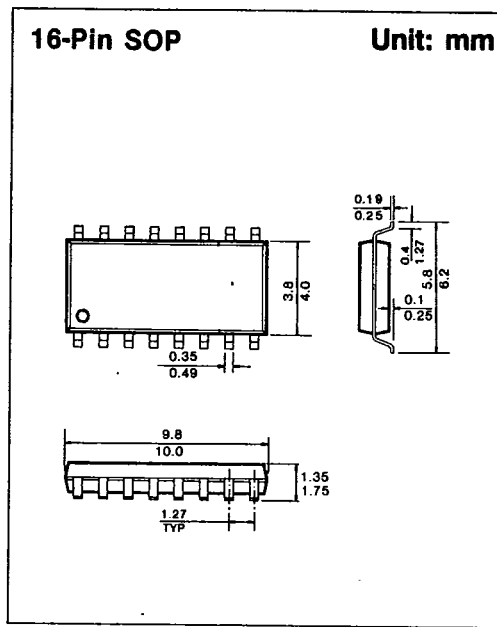
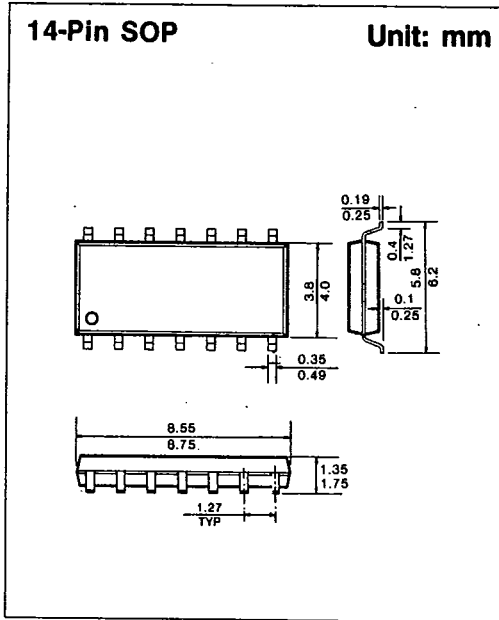
SAMSUNG SEMICONDUCTOR

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PACKAGE DIMENSIONS

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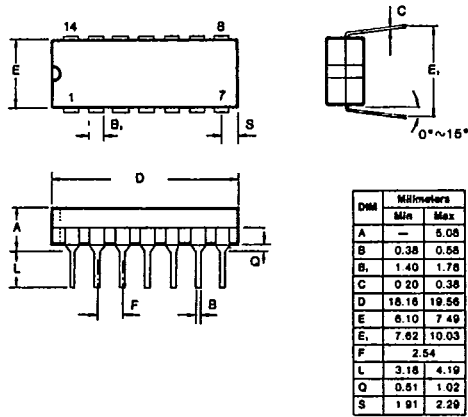


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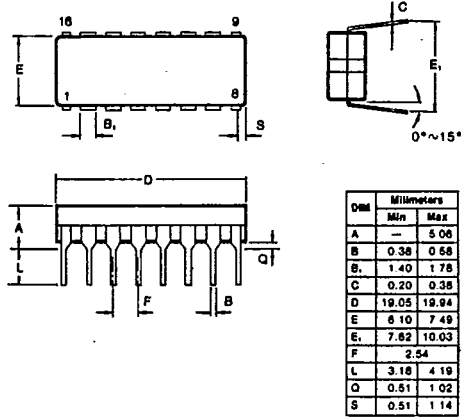
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2. CERAMIC PACKAGES

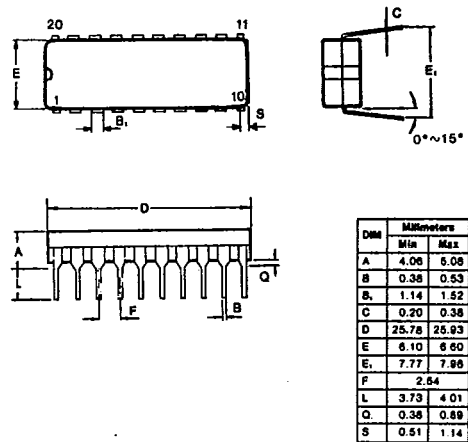
14-Pin Ceramic DIP Units: mm



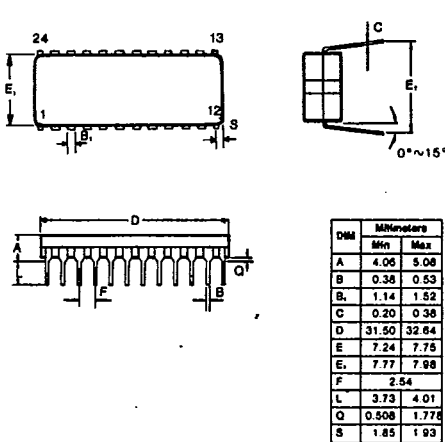
16-Pin Ceramic DIP Units: mm



20-Pin Ceramic DIP Units: mm



24-Pin Ceramic DIP Units: mm



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